Features: Compact moisture resistant package

Lowest "on" resistance

Low distortion

Ideal for Hi-Fi stereo applications

Storage Temperature:

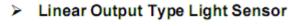
-30 to+80 C

Operating Temperature:

-30 to+80 C 260 C <10s

Soldering Temperature: Isolation Voltage(peak):

2000V





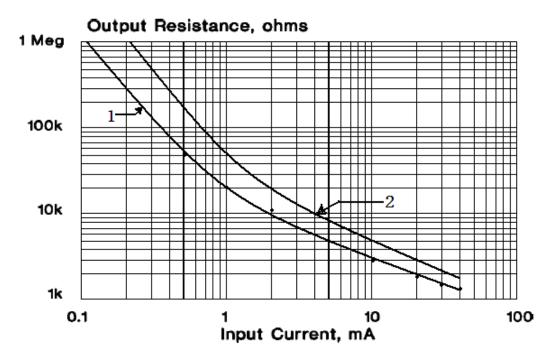
Symbol	Parameter	Min	Тур	Max	Units	TestConditions
LED						
ĬF	Forward Current			40	mA	(Derate Linearly to 0 at 75°C)
VF	Forward Voltage			2.5	V	IF = 16 mA
IR	Reverse Current			100	μΑ	VR=3.8V
Cell						
Vc	Maximum Cell Voltage			60	V	(Peak AC or DC)
PD	Power Dissipation			50	mW	(Derate Linearly to 0 at 75° C)
Coupled						
Ron	On Resistance	4. 0		7.0	ΚΩ	IF = 0.5 mA**
Roff	Off Resistance	10.0			ΜΩ	10sec after I=0.3Vdc on cell
Tr	Rise Time			2.5	msec	Time to 63% of final conductance @ IF = 16 mA ***
TF	Decay Time			35	msec	Time to $100 \text{K}\Omega$ after removal of input @ IF = 16 mA
	Cell Temp Coefficient		1.0		%℃	IF>5 mA

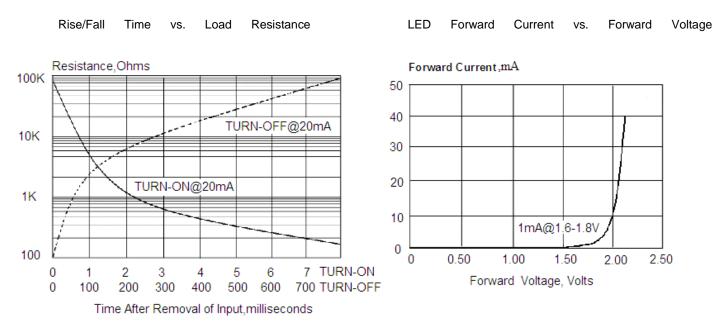
^{* 2}mm from case for < 5 sec

^{* *} measured after a dark history of 1 week

^{* * *} Rise time is the time for the dark change in conductance to reach 63% of its final value

Output Resistance vs. Forward Current





Dimensional Outline and Connection(Unit:mm)

